

ESD5V0SxUS

Multi-Channel TVS Diode Array

- ESD / transient protection of data and power lines in 3.3 V / 5 V application according to: IEC61000-4-2 (ESD): ± 30 KV (contact) IEC61000-4-4 (EFT): 80 A (5/50 ns) IEC61000-4-5 (Surge): 10 A (8/20 µs)
- Working voltage: 5 V (5.3 V max.)
- Low clamping voltage
- Low reverse current < 5 μ A
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101

Applications

- Uni or bi-directional operation possible (see application example page 5)
- Mobile communication
- Consumer products (STB, MP3, DVD, DSC...)
- LCD displays, camera
- Notebooks and desktop computers, peripherals



ESD5V0S4US

ESD5V0S5US

ESD5V0S5US E6727

180° rotated in reel

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		¥
4	g	9

Туре	Package	Configuration	Marking
ESD5V0S4US	SOT363	4 lines, uni-directional	E4s
ESD5V0S5US	SOT363	5 lines, uni-directional	E5s
ESD5V3S5US E6727*	SOT363	5 lines, uni-directional	on request

* Preliminary data

TET



Maximum Ratings at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit	
ESD contact discharge per diode ¹⁾	V _{ESD}	30	kV	
Peak pulse current ($t_p = 8 / 20 \ \mu s$) per diode ²)	I _{pp}	10	А	
Peak pulse power ($t_p = 8 / 20 \ \mu s$) per diode	P _{pk}	130	W	
Operating temperature range	T _{op}	-55125	°C	
Storage temperature	T _{sta}	-65150		

Electrical Characteristics at $T_A = 25^{\circ}C$, unless otherwise specified

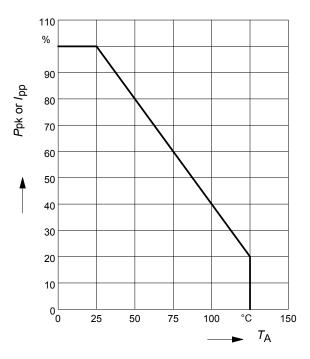
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
Characteristics				•	
Reverse working voltage	V _{RWM}	-	5	5.3	V
Breakdown voltage	V _(BR)	5.7	6.7	7.7	
<i>l</i> _(BR) = 1 mA					
Reverse current	I _R				μA
V _R = 3.3 V		-	-	1	
V_{R} = 5 V		-	-	5	
Clamping voltage (positive transients)	V _{CL}				V
$I_{\rm PP}$ = 1 A, $t_{\rm p}$ = 8/20 µs ²)		-	7	9	
$I_{\rm PP}$ = 10 A, $t_{\rm p}$ = 8/20 µs ²⁾		-	10.5	13	
Forward clamping voltage (negative transients)	V _{FC}				
$I_{\rm PP}$ = 1 A, $t_{\rm p}$ = 8/20 µs ²⁾		-	1	3	
$I_{\rm PP} = 10 \text{ A}, t_{\rm p} = 8/20 \ \mu \text{s}^{2)}$		-	3.5	6	
Diode capacitance	CT				pF
$V_{\rm R}$ = 0 V, <i>f</i> = 1 MHz		-	70	90	
$V_{\rm R}$ = 5 V, <i>f</i> = 1 MHz		-	35	55	

 $^{1}V_{\text{ESD}}$ according to IEC61000-4-2

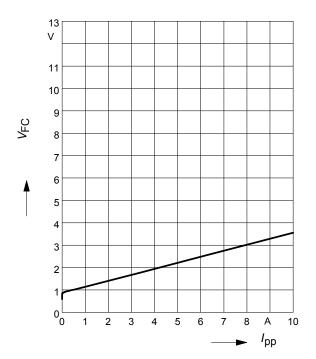
 $^{2}I_{pp}$ according to IEC61000-4-5



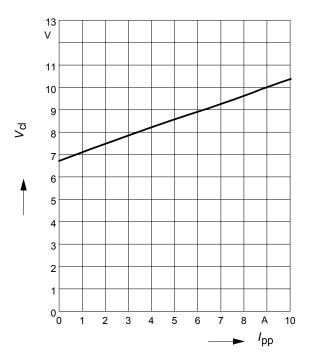
Power derating curve $P_{pk} = f(T_A)$



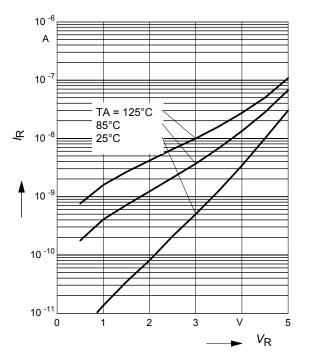
Forward clamping voltage $V_{FC} = f(I_{pp})$ $t_p = 8 / 20 \ \mu s$ (negative transients)



Clamping voltage, $V_{cl} = f(I_{pp})$ $t_p = 8 / 20 \ \mu s$ (positive transients)



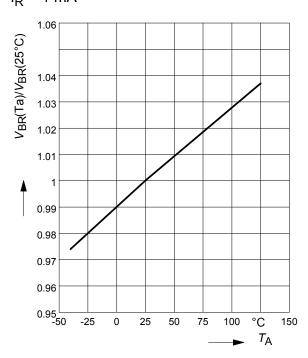
Reverse current $I_{R} = f(V_{R})$ T_{A} = Parameter





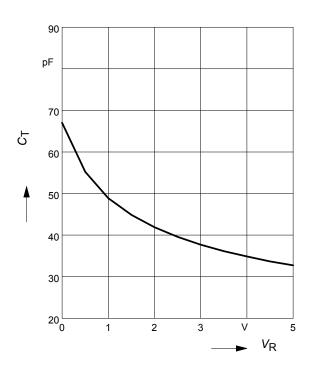
Normalized reverse voltage

 $V_{BR}(T_A)/V_{BR}(25^{\circ}C)=f(T_A)$ $I_R = 1 \text{ mA}$



Diode capacitance $C_{T} = f(V_{R})$

f = 1 MHz

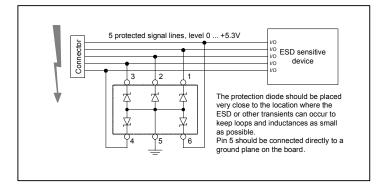


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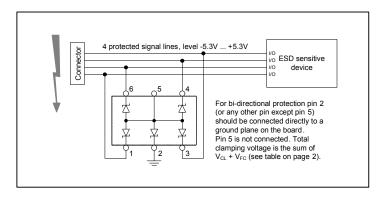
Application example ESD5V0S5US

5 channels, uni-directional



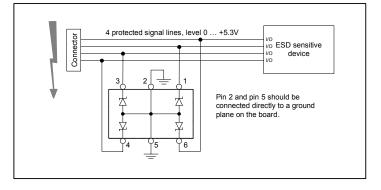
Application example ESD5V0S5US

4 channels, bi-directional

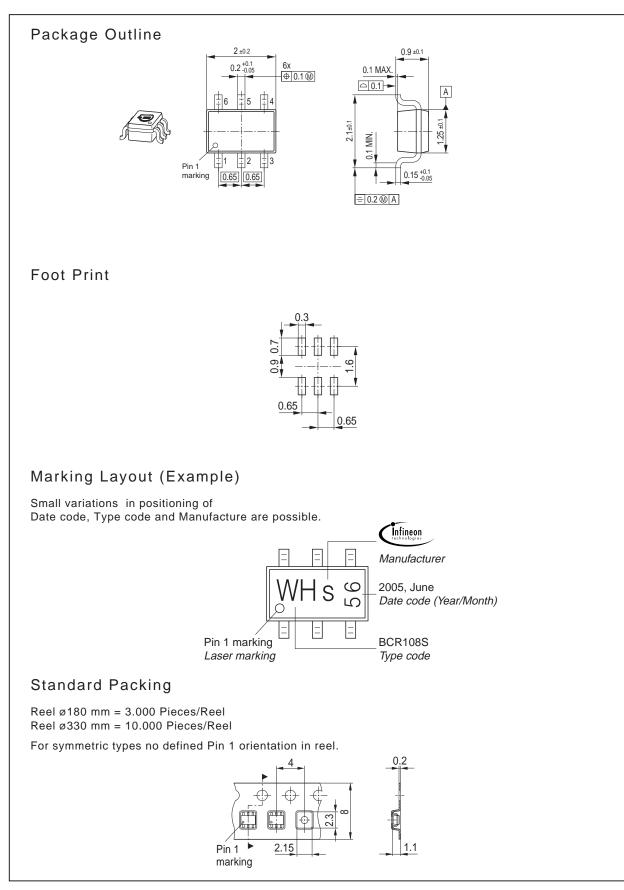


Application example ESD5V0S4US

4 channels, uni-directional









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